2SCR543R

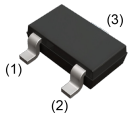
NPN 3.0A 50V Middle Power Transistor

Datasheet

Parameter	Value
V_{CEO}	50V
I_C	3A

●Outline

SOT-346T
SC-96

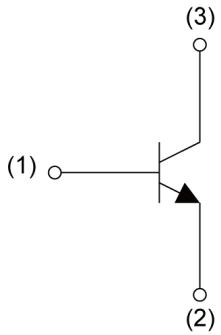


TSMT3

●Features

1)Suitable for Middle Power Transistor
2) Complementary PNP Types:2SAR543R
3) Low saturation voltage, typically
$V_{CE(sat)}$=350mV(Max.)
(I_C/I_B=2A/100mA)

●Inner circuit



(1) Base
(2) Emitter
(3) Collector

●Application

LOW FREQUENCY AMPLIFIER, HIGH SPEED SWITCHING

●Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SCR543R	SOT-346T (TSMT3)	2928	TL	180	8	3000	NR

●Absolute maximum ratings (T_a = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V_{EBO}	6	V
Collector current	I_C	3	A
	I_{CP} *1	6	A
Power dissipation	P_D *2	0.5	W
	P_D *3	1.0	W
Junction temperature	T_j	150	℃
Range of storage temperature	T_{stg}	-55 to +150	℃

●Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Collector-base breakdown voltage	BV_{CBO}	I_C = 100μA	50	-	-	V
Collector-emitter breakdown voltage	BV_{CEO}	I_C = 1mA	50	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I_E = 100μA	6	-	-	V
Collector cut-off current	I_{CBO}	V_{CB} = 50V	-	-	1.0	μA
Emitter cut-off current	I_{EBO}	V_{EB} = 4V	-	-	1.0	μA
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C = 2A, I_B = 100mA	-	130	350	mV
DC current gain	h_{FE}	V_{CE} = 3V, I_C = 100mA	180	-	450	-
Transition frequency	f_T	V_{CE} = 10V, I_E = -500mA, f = 100MHz	-	300	-	MHz
Output capacitance	C_{ob}	V_{CB} = 10V, I_E = 0A, f = 1MHz	-	20	-	pF
Turn-On time	t_{on}	I_C = 2A, I_{B1} = 200mA, I_{B2} = -200mA, V_{CC} ≃ 10V, R_L = 4.7Ω See test circuit	-	50	-	ns
Storage time	t_{stg}		-	450	-	ns
Fall time	t_f		-	85	-	ns

*1 P_W=10ms, Single pulse

*2 Each terminal mounted on a reference land.

*3 Mounted on a 40×40×0.7mm ceramic board.

●Electrical characteristic curves(T_a = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

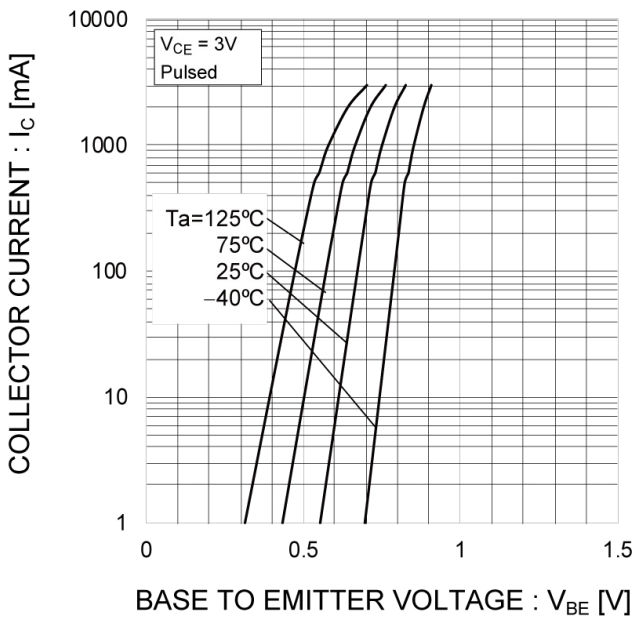


Fig.2 Typical Output Characteristics

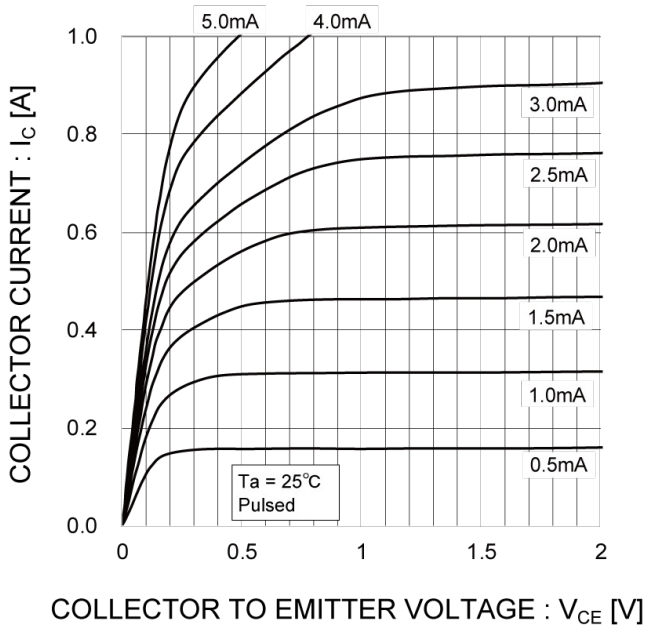


Fig.3 DC Current Gain vs. Collector Current (I)

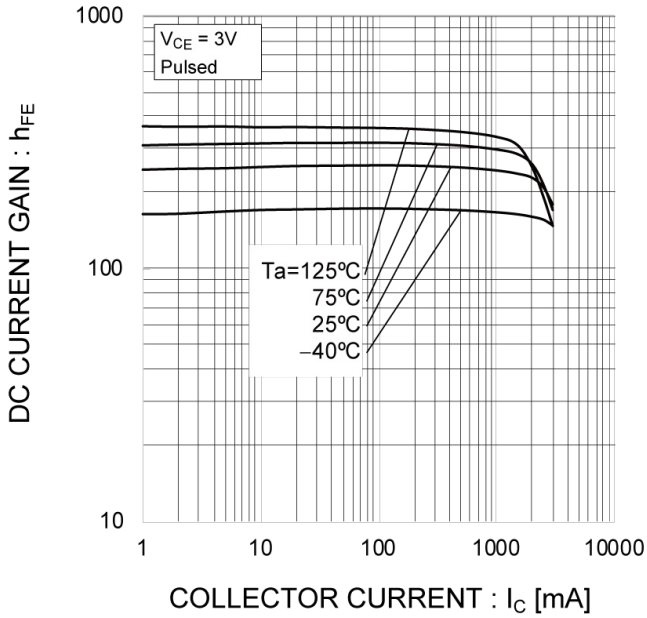
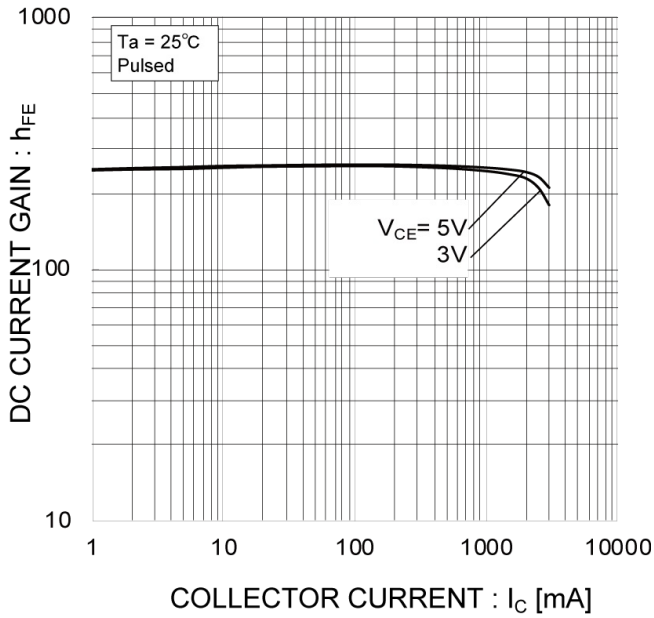


Fig.4 DC Current Gain vs. Collector Current (II)



●Electrical characteristic curves(T_a = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

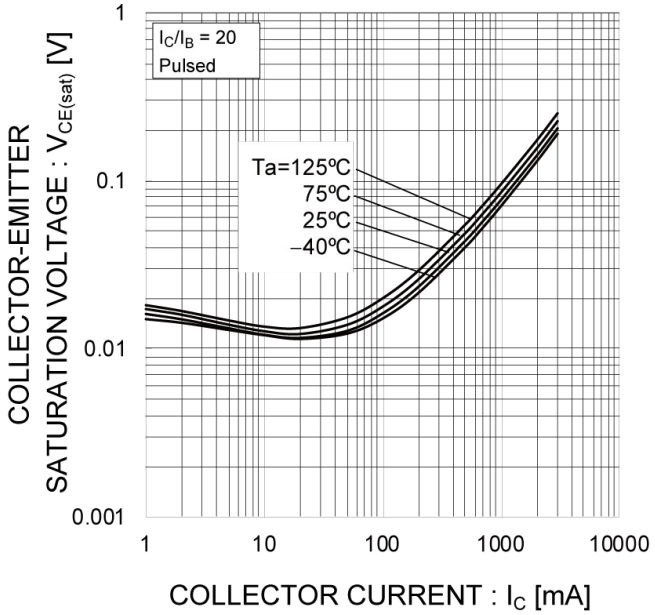


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

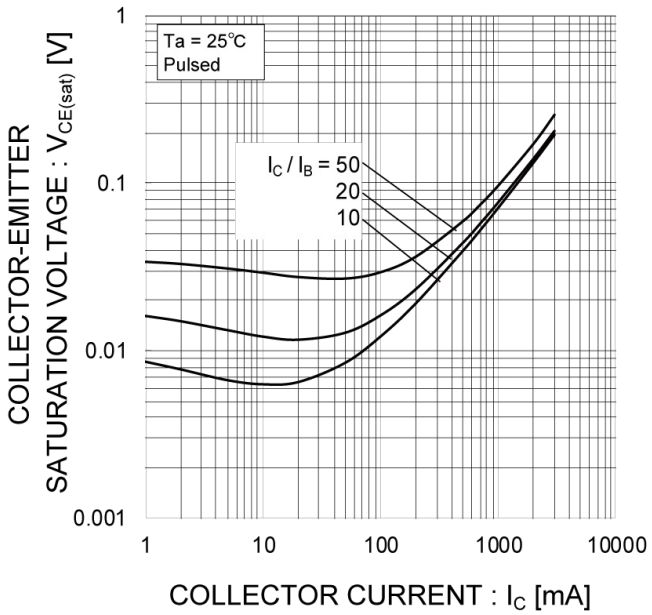


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

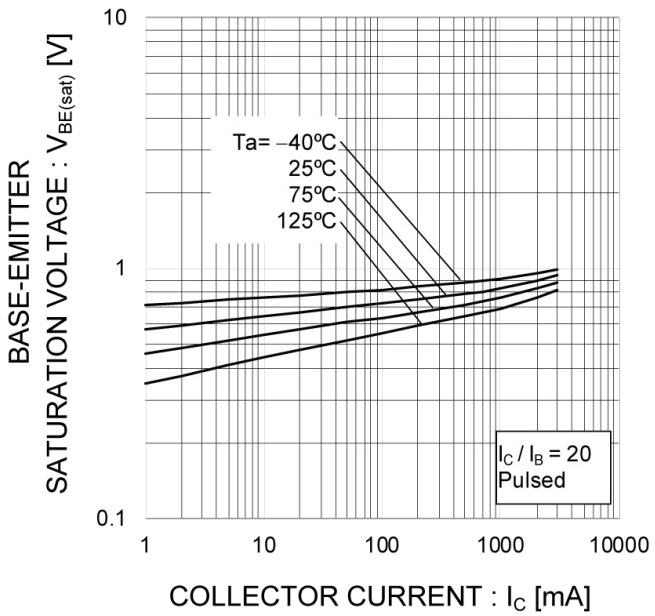
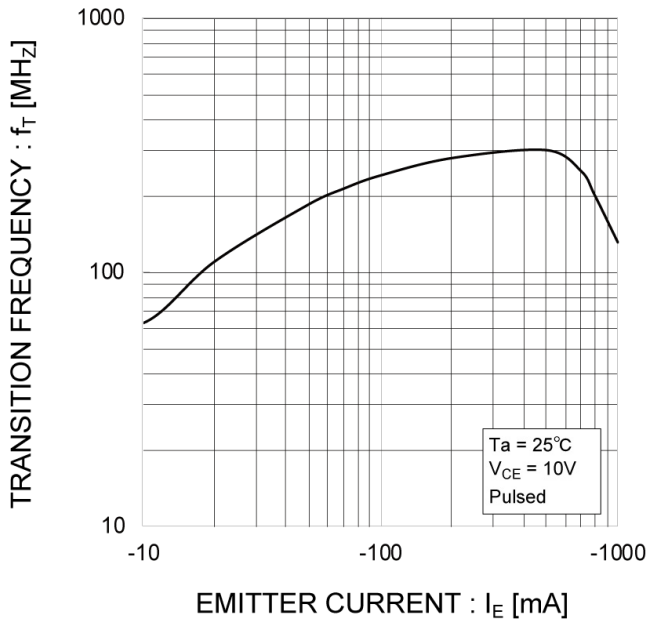


Fig.8 Gain Bandwidth Product vs. Emitter Current



●Electrical characteristic curves(T_a = 25°C)

Fig.9 Emitter Input Capacitance vs. Emitter-Base Voltage
Collector Output Capacitance vs. Collector-Base Voltage

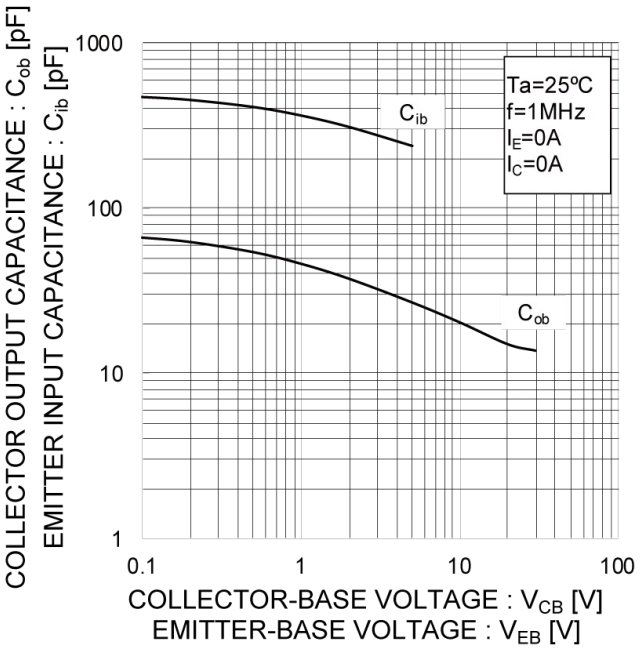
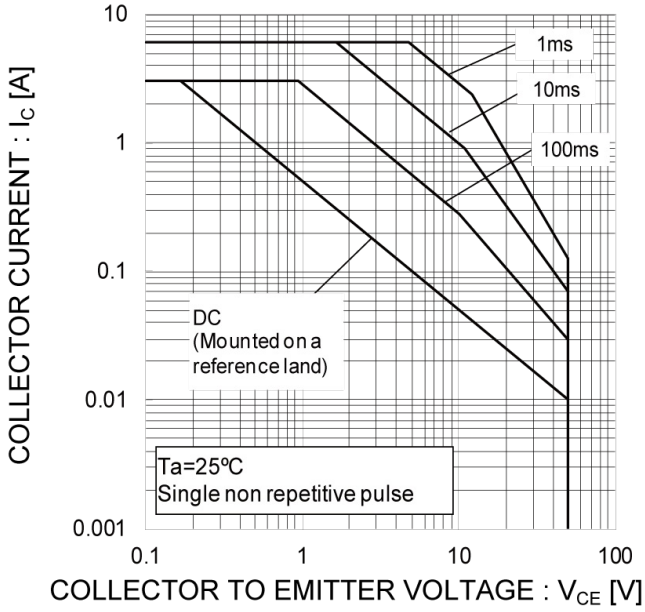
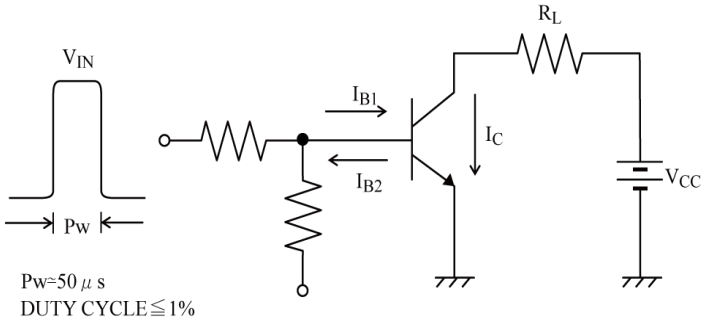
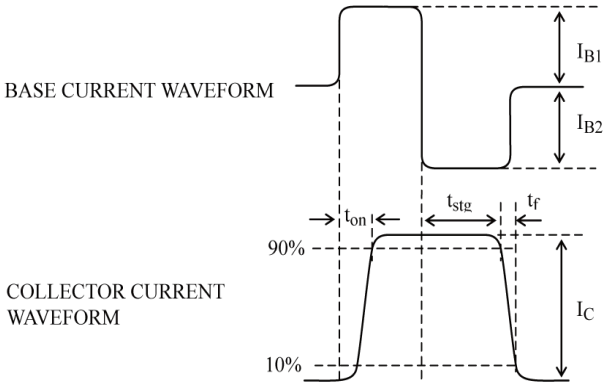


Fig.10 Safe Operating Area



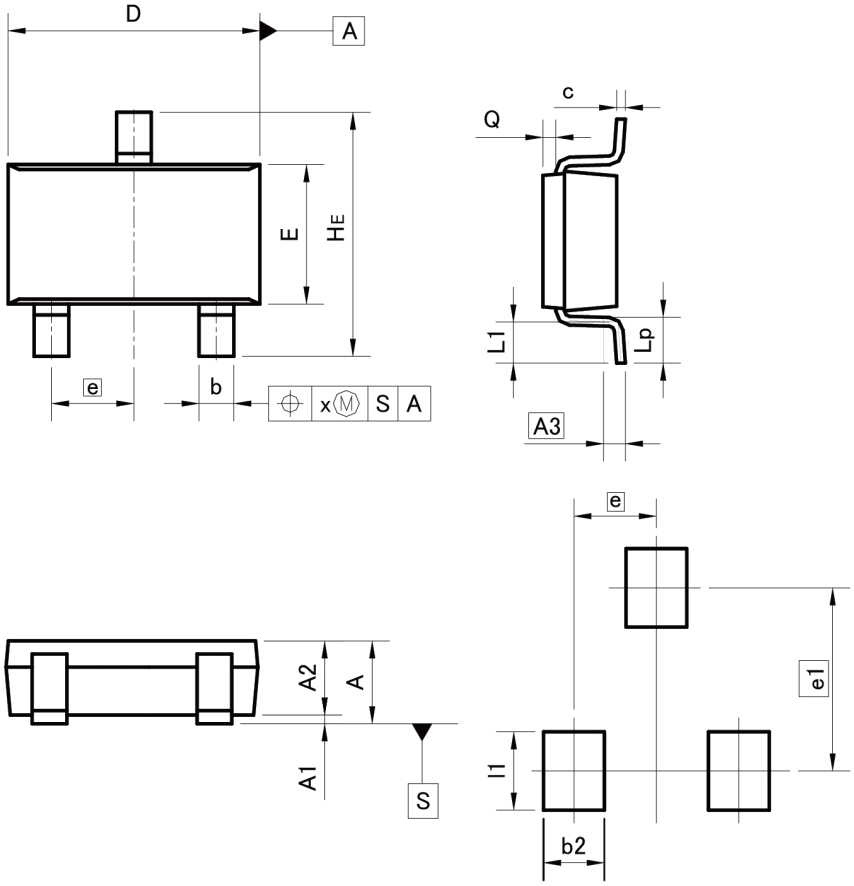
SWITCHING TIME TEST CIRCUIT





●Dimensions

TSMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	–	1.00	–	0.039
A1	0.00	0.10	0.000	0.004
A2	0.75	0.95	0.030	0.037
A3	0.25		0.010	
b	0.35	0.50	0.014	0.020
c	0.10	0.26	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
e	0.95		0.037	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.05	0.25	0.002	0.010
x	–	0.20	–	0.008

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2		0.70	–	0.028
e1	2.10		0.083	
l1	–	0.90	–	0.035

Dimension in mm/inches

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- Техническая поддержка проекта;
- Защита от снятия компонента с производства.

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